

# **RJH1CV5DPK**

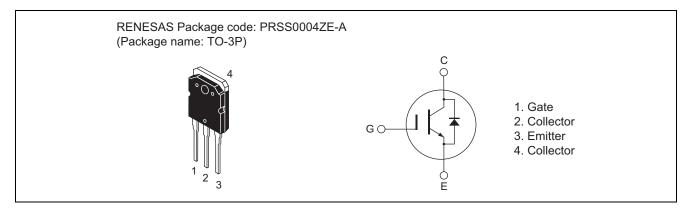
1200V - 25A - IGBT Application: Inverter

R07DS0746EJ0300 Rev.3.00 Feb 14, 2013

#### **Features**

- Short circuit withstand time (5 µs typ.)
- Low collector to emitter saturation voltage  $V_{CE(sat)} = 1.8 \text{ V}$  typ. (at  $I_C = 25 \text{ A}$ ,  $V_{GE} = 15 \text{ V}$ ,  $Ta = 25^{\circ}\text{C}$ )
- Built-in fast recovery diode ( $t_{rr} = 170 \text{ ns typ.}$ ) in one package
- Trench gate and thin wafer technology
- High speed switching  $t_f=165 \text{ ns typ. (at } V_{CC}=600 \text{ V}, V_{GE}=15 \text{ V}, I_C=25 \text{ A}, Rg=5 \Omega, Ta=25 ^{\circ}\text{C, inductive load)}$

#### **Outline**



### **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

Item		Symbol	Ratings	Unit
Collector to emitter voltage / diode reverse voltage		V <sub>CES</sub> / V <sub>R</sub>	1200	V
Gate to emitter voltage		$V_{GES}$	±30	V
Collector current	Tc = 25°C	Ic	50	Α
	Tc = 100°C	Ic	25	А
Collector peak current		ic(peak) Note1	75	Α
Collector to emitter diode forward current		I <sub>DF</sub>	25	Α
Collector to emitter diode forward peak current		i <sub>DF</sub> (peak) Note1	75	Α
Collector dissipation		P <sub>C</sub> Note2	245	W
Junction to case thermal resistance (IGBT)		θj-c Note2	0.51	°C/W
Junction to case thermal resistance (Diode)		θj-cd <sup>Note2</sup>	0.69	°C/W
Junction temperature		Tj	150	°C
Storage temperature		Tstg	-55 to +150	°C

Notes: 1. PW  $\leq$  10  $\mu$ s, duty cycle  $\leq$  1%

2. Value at Tc = 25°C

### **Electrical Characteristics**

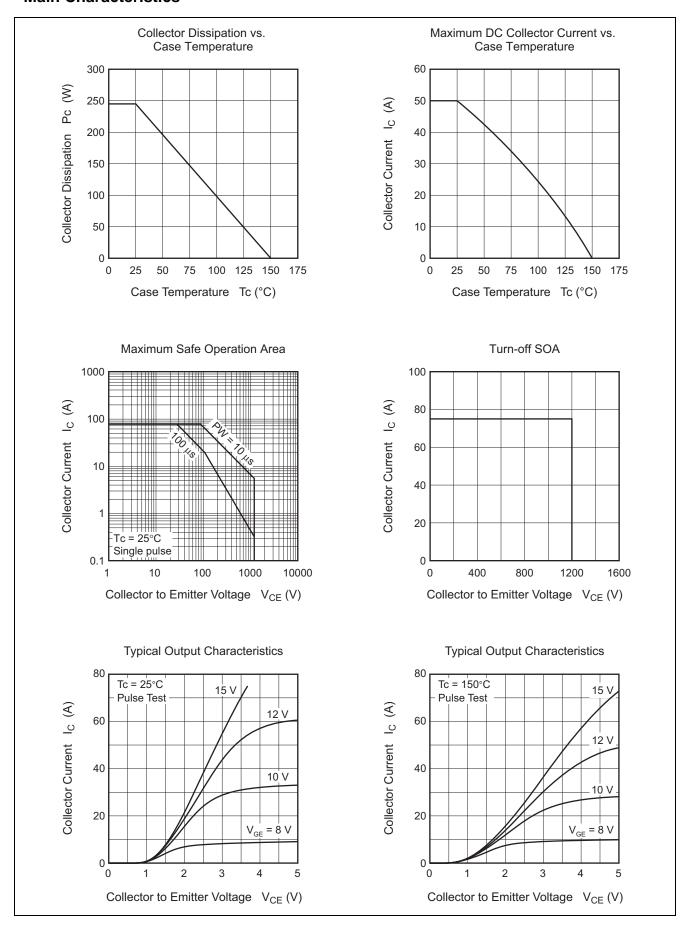
 $(Ta = 25^{\circ}C)$ 

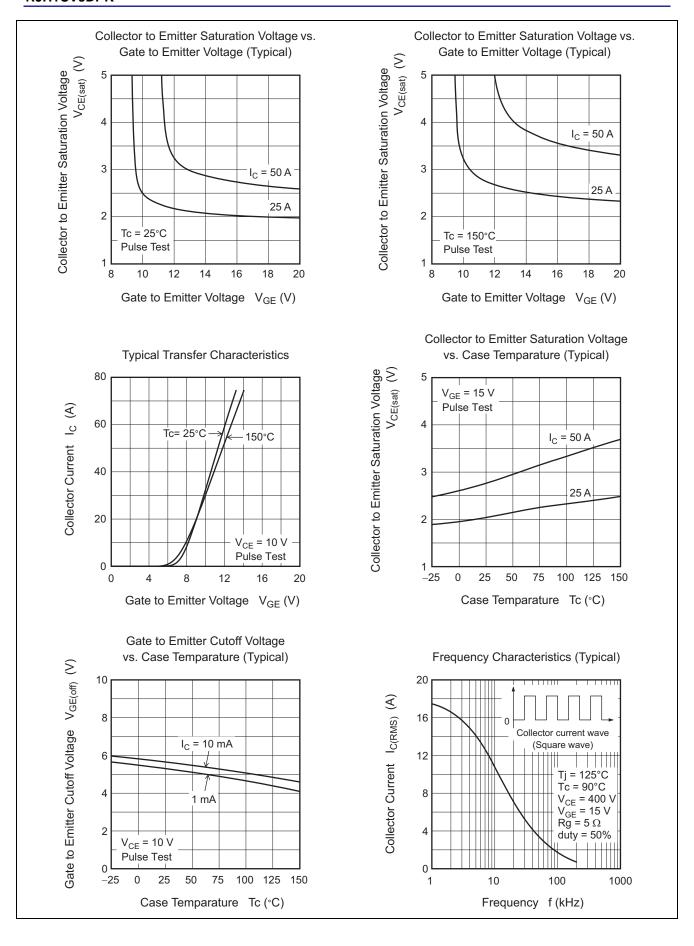
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Zero gate voltage collector current / Diode reverse current	I <sub>CES</sub> /I <sub>R</sub>	_	_	5	μА	V <sub>CE</sub> = 1200 V, V <sub>GE</sub> = 0
Gate to emitter leak current	I <sub>GES</sub>	_	_	±1	μА	$V_{GE} = \pm 30 \text{ V}, V_{CE} = 0$
Gate to emitter cutoff voltage	$V_{GE(off)}$	4.5	_	6.5	V	$V_{CE} = 10 \text{ V}, I_{C} = 1 \text{ mA}$
Collector to emitter saturation voltage	V <sub>CE(sat)</sub>	_	1.8	2.6	V	$I_C = 25 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$
	V <sub>CE(sat)</sub>	_	2.8	_	V	$I_C = 50 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$
Input capacitance	Cies	_	1150	_	pF	V <sub>CE</sub> = 25 V
Output capacitance	Coes	_	70	_	pF	V <sub>GE</sub> = 0 f = 1 MHz
Reverse transfer capacitance	Cres	_	30	_	pF	
Total gate charge	Qg	_	72	_	nC	V <sub>GE</sub> = 15 V V <sub>CE</sub> = 300 V I <sub>C</sub> = 25 A
Gate to emitter charge	Qge	_	8	_	nC	
Gate to collector charge	Qgc	_	40	_	nC	
Turn-on delay time	t <sub>d(on)</sub>	_	42	_	ns	$V_{CC} = 600 \text{ V}$ $V_{GE} = 15 \text{ V}$ $I_{C} = 25 \text{ A}$ $Rg = 5 \Omega$ Inductive load
Rise time	t <sub>r</sub>	_	24	_	ns	
Turn-off delay time	t <sub>d(off)</sub>	_	105	_	ns	
Fall time	t <sub>f</sub>	_	165	_	ns	
Turn-on energy	Eon	_	1.9	_	mJ	
Turn-off energy	E <sub>off</sub>	_	1.5	_	mJ	
Total switching energy	E <sub>total</sub>	_	3.4	_	mJ	
Short circuit withstand time	t <sub>sc</sub>	_	5	_	μѕ	$\begin{aligned} &V_{CC} \leq 720 \text{ V, } V_{GE} = 15 \text{ V} \\ &Tc \leq 125^{\circ}C \end{aligned}$
FRD forward voltage	V <sub>F</sub>		1.8		V	I <sub>F</sub> = 25 A <sup>Note3</sup>
FRD reverse recovery time	t <sub>rr</sub>	_	170	_	ns	I <sub>F</sub> = 25 A

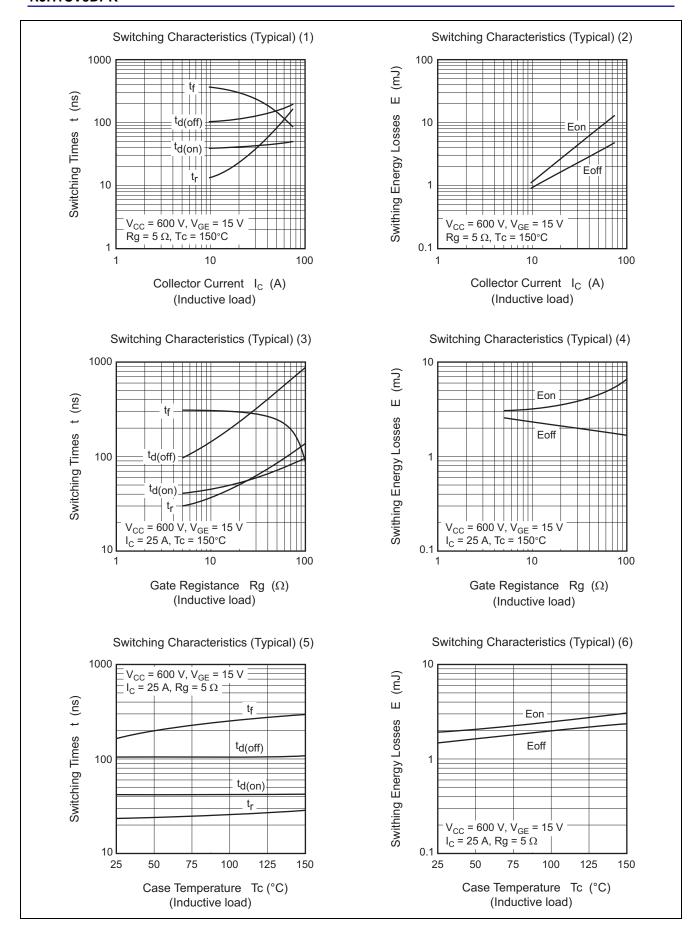
FRD forward voltage	$V_{F}$	_	1.8	_	V	$I_F = 25 A^{\text{Note3}}$
FRD reverse recovery time	t <sub>rr</sub>	_	170	_	ns	I <sub>F</sub> = 25 A
FRD reverse recovery charge	Q <sub>rr</sub>	_	0.62	_	μС	$di_F/dt = 100 A/\mu s$
FRD peak reverse recovery current	I <sub>rr</sub>	_	9.2	_	Α	

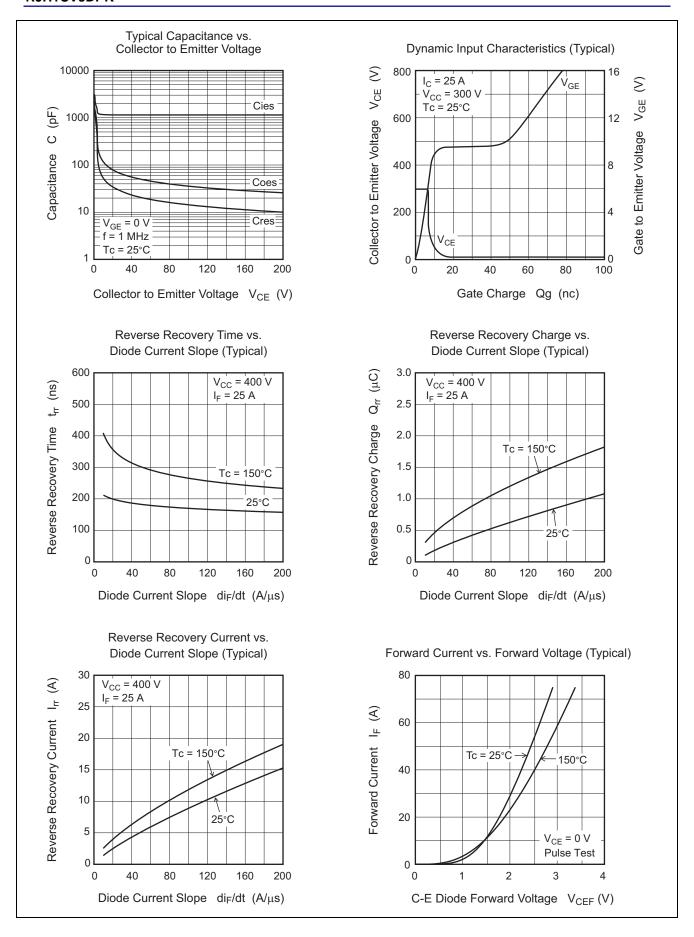
Notes: 3. Pulse test.

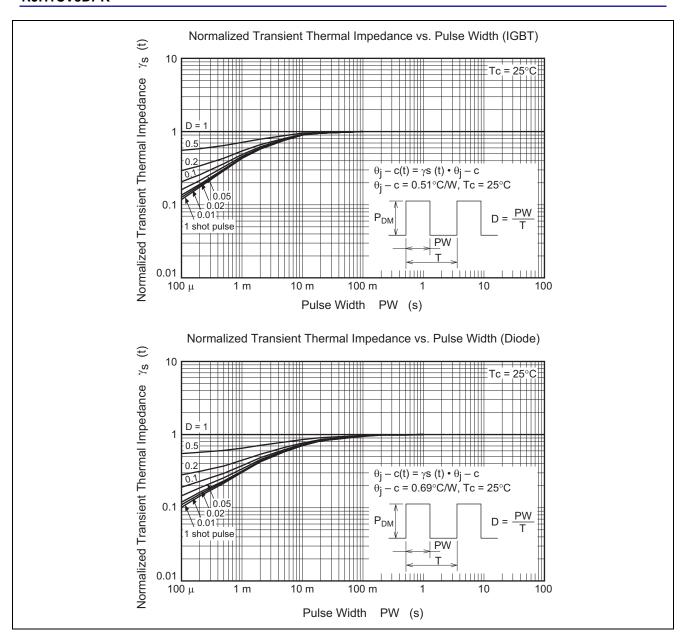
#### **Main Characteristics**

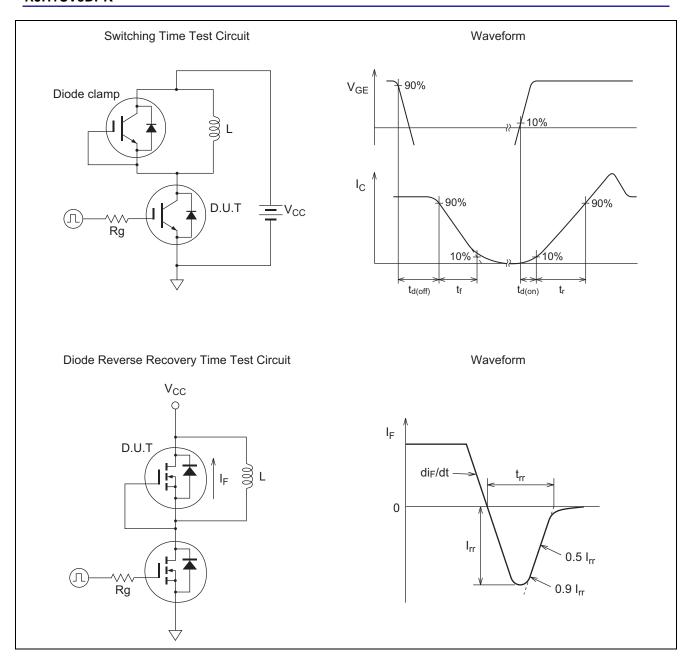




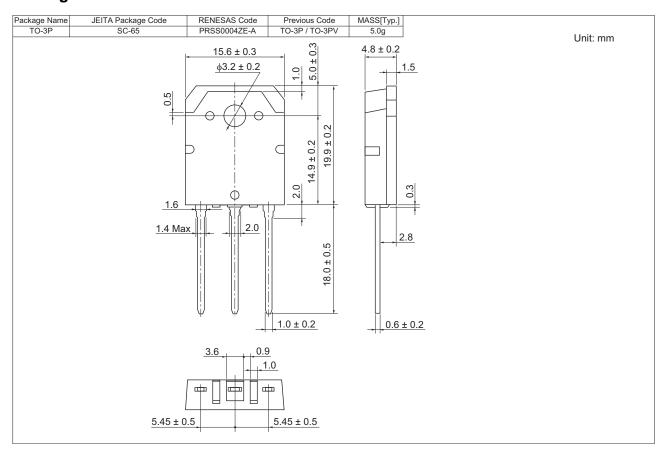








### **Package Dimension**



### **Ordering Information**

Orderable Part Number	Quantity	Shipping Container		
RJH1CV5DPK-00#T0	30 pcs	Tube		

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